# **Dual Non-Inverting Buffer, Open Drain**

The NLX2G07 MiniGate<sup>™</sup> is an advanced high-speed CMOS dual non-inverting buffer with open drain output in ultra-small footprint. The NLX2G07 input and output structures provide protection when voltages up to 7.0 V are applied, regardless of the supply voltage.

#### **Features**

- High Speed:  $t_{PD} = 2.3 \text{ ns (Typ)} @ V_{CC} = 5.0 \text{ V}$
- Low Power Dissipation:  $I_{CC} = 1 \mu A$  (Max) at  $T_A = 25^{\circ}C$
- Power Down Protection Provided on inputs
- Balanced Propagation Delays
- Overvoltage Tolerant (OVT) Input and Output Pins
- Ultra-Small Packages
- These are Pb-Free Devices

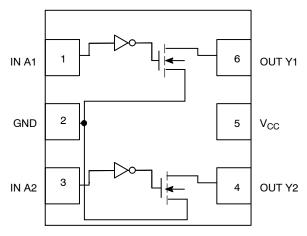


Figure 1. Pinout (Top View)

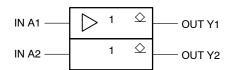


Figure 2. Logic Symbol

#### **PIN ASSIGNMENT**

# A Y L L

Z

Н

1	IN A1		
2	GND		
3	IN A2		
4	OUT Y2		
5	V <sub>CC</sub>		
6	OUT Y1		



#### ON Semiconductor®

http://onsemi.com

#### MARKING DIAGRAMS



ULLGA6 1.0 x 1.0 CASE 613AD





ULLGA6 1.2 x 1.0 CASE 613AE





ULLGA6 1.45 x 1.0 CASE 613AF





UDFN6 1.0 x 1.0 CASE 517BX





UDFN6 1.2 x 1.0 CASE 517AA





UDFN6 1.45 x 1.0 CASE 517AQ



R, A, K, V = Device Marking M = Date Code

#### ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 5 of this data sheet.

#### **MAXIMUM RATINGS**

Symbol	Parame	Value	Unit	
V <sub>CC</sub>	DC Supply Voltage	-0.5 to +7.0	٧	
V <sub>IN</sub>	DC Input Voltage		-0.5 to +7.0	٧
V <sub>OUT</sub>	DC Output Voltage		-0.5 to +7.0	٧
I <sub>IK</sub>	DC Input Diode Current	V <sub>IN</sub> < GND	-50	mA
l <sub>ok</sub>	DC Output Diode Current	-50	mA	
I <sub>O</sub>	DC Output Source/Sink Current	±50	mA	
I <sub>CC</sub>	DC Supply Current Per Supply Pin	±100	mA	
I <sub>GND</sub>	DC Ground Current per Ground Pin	±100	mA	
T <sub>STG</sub>	Storage Temperature Range	−65 to +150	°C	
$T_L$	Lead Temperature, 1 mm from Case for 10 S	Seconds	260	°C
TJ	Junction Temperature Under Bias	150	°C	
MSL	Moisture Sensitivity	Level 1		
F <sub>R</sub>	Flammability Rating Oxygen	UL 94 V-0 @ 0.125 in		
I <sub>LATCHUP</sub>	Latchup Performance Above V <sub>CC</sub> and Below	±500	mA	

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

1. Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2 ounce copper trace no air flow.

2. Tested to EIA/JESD22-A114-A.

- 3. Tested to EIA/UESD22-A115-A.
- 4. Tested to JESD22-C101-A.
- 5. Tested to EIA / JESD78.

#### RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Min	Max	Unit
V <sub>CC</sub>	Positive DC Supply Voltage	1.65	5.5	V
V <sub>IN</sub>	Digital Input Voltage	0	5.5	V
V <sub>OUT</sub>	Output Voltage	0	5.5	V
T <sub>A</sub>	Operating Free-Air Temperature	-55	+125	°C
Δt/ΔV	Input Transition Rise or Fall Rate $ V_{CC} = 3.3 \text{ V} \pm 0.3 \text{ V}  $ $ V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V} $	0 0	100 20	ns/V

#### DC ELECTRICAL CHARACTERISTICS

			V <sub>CC</sub>	/ <sub>CC</sub>		<b>T</b> <sub>A</sub> = -	+85°C		55°C to 5°C		
Symbol	Parameter	Conditions	(V)	Min	Тур	Max	Min	Max	Min	Max	Unit
V <sub>IH</sub>	Low-Level Input Voltage		1.65- 1.95	0.75 x V <sub>CC</sub>			0.75 x V <sub>CC</sub>		0.75 x V <sub>CC</sub>		V
			2.3 to 5.5	0.70 x V <sub>CC</sub>			0.70 x V <sub>CC</sub>		0.70 x V <sub>CC</sub>		
V <sub>IL</sub>	Low-Level Input Voltage		1.65- 1.95			0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>		0.25 x V <sub>CC</sub>	V
			2.3 to 5.5			0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>		0.30 x V <sub>CC</sub>	
V <sub>OL</sub>	Low-Level Output Voltage	$V_{IN} = V_{IH} \text{ or } V_{IL}$ $I_{OL} = 50 \mu A$	1.65- 5.5			0.1		0.1		0.1	V
	voltage	$\begin{aligned} &V_{IN} = V_{IH} \text{ or } V_{IL} \\ &I_{OL} = 4 \text{ mA} \\ &I_{OL} = 8 \text{ mA} \\ &I_{OL} = 12 \text{ mA} \\ &I_{OL} = 16 \text{ mA} \\ &I_{OL} = 24 \text{ mA} \\ &I_{OL} = 32 \text{ mA} \end{aligned}$	1.65 2.3 2.7 3.0 3.0 4.5		0.08 0.2 0.22 0.28 0.38 0.42	0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55		0.24 0.3 0.4 0.4 0.55 0.55	
I <sub>LKG</sub>	Z-State Output Leakage Current	$\begin{aligned} V_{IN} &= V_{IH}, \\ V_{OUT} &= V_{CC} \text{ or } \\ GND \end{aligned}$	5.5			±5.0		±10		±10	μΑ
I <sub>IN</sub>	Input Leakage Current	$0 \le V_{IN} \le 5.5 V$	0 to 5.5			±0.1		±1.0		±1.0	μΑ
l <sub>OFF</sub>	Power Off Input Leakage Current	$0 \le V_{IN}, \\ V_{OUT} \le 5.5 \text{ V}$	0			1.0		10		10	μΑ
I <sub>CC</sub>	Quiescent Supply Current	V <sub>IN</sub> = 0 or V <sub>CC</sub>	5.5			1.0		10		10	μΑ

#### AC ELECTRICAL CHARACTERISTICS (Input $t_r = t_f = 3.0 \text{ nS}$ )

		V <sub>CC</sub>	Test	Т	T <sub>A</sub> = 25 °C		T <sub>A</sub> = -55°C to +125°C		
Symbol	Parameter	(V)	Condition	Min	Тур	Max	Min	Max	Unit
t <sub>PZL</sub>	Propagation Delay (Figures 3 and 4)	1.65–1.95	$R_L = R_1 = 5000 \Omega,$ $C_L = 15 pF$	1.8	5.3	11.5	1.8	12	ns
		2.3-2.7	$R_L = R_1 = 500 \Omega,$ $C_L = 50 pF$	1.2	3.7	5.8	1.2	6.4	
		3.0-3.6	$R_L = R_1 = 500 \Omega,$ $C_L = 50 pF$	0.8	2.9	4.4	0.8	4.8	
		4.5-5.5	$R_L = R_1 = 500 \Omega,$ $C_L = 50 pF$	0.5	2.3	3.5	0.5	3.9	
t <sub>PLZ</sub>	Propagation Delay (Figures 3 and 4)	1.65–1.95	$R_L = R_1 = 5000 \Omega,$ $C_L = 15 pF$	1.8	5.3	11.5	1.8	12	ns
		2.3-2.7	$R_L = R_1 = 500 \Omega,$ $C_L = 50 \text{ pF}$	1.2	2.8	5.8	1.2	6.4	
		3.0-3.6	$R_L = R_1 = 500 \Omega,$ $C_L = 50 \text{ pF}$	0.8	2.1	4.4	0.8	4.8	
		4.5-5.5	$R_L = R_1 = 500 \Omega,$ $C_L = 50 pF$	0.5	1.4	3.5	0.5	3.9	
C <sub>IN</sub>	Input Capacitance	5.5	V <sub>IN</sub> = 0 V or V <sub>CC</sub>		2.5				pF
C <sub>OUT</sub>	Output Capacitance	5.5	V <sub>IN</sub> = 0 V or V <sub>CC</sub>		4				pF
C <sub>PD</sub>	Power Dissipation Capacitance (Note 6)	3.3 5.5	10 MHz V <sub>IN</sub> = 0 V or V <sub>CC</sub>		4				pF

<sup>6.</sup> C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the dynamic operating current consumption without load. Average operating current can be obtained by the equation I<sub>CC(OPR)</sub> = C<sub>PD</sub> • V<sub>CC</sub> • f<sub>in</sub> + I<sub>CC</sub>. C<sub>PD</sub> is used to determine the no–load dynamic power consumption: P<sub>D</sub> = C<sub>PD</sub> • V<sub>CC</sub><sup>2</sup> • f<sub>in</sub> + I<sub>CC</sub> • V<sub>CC</sub>.

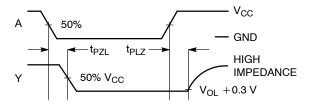
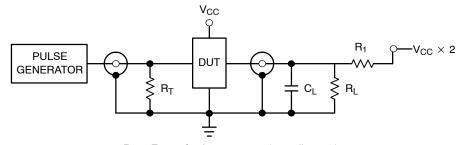


Figure 3. Switching Waveforms



 $R_T = Z_{OUT}$  of pulse generator (typically 50  $\Omega$ )

Figure 4. Test Circuit

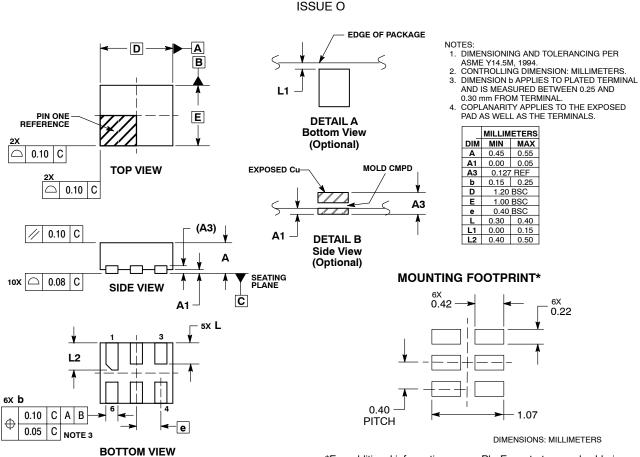
#### **ORDERING INFORMATION**

Device	Package	Shipping <sup>†</sup>
NLX2G07AMX1TCG	ULLGA6, 1.45 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel
NLX2G07BMX1TCG	ULLGA6, 1.2 x 1.0, 0.4P (Pb-Free)	3000 / Tape & Reel
NLX2G07CMX1TCG	ULLGA6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel
NLX2G07MUTCG*	UDFN6, 1.2 x 1.0, 0.4P (Pb-Free)	3000 / Tape & Reel
NLX2G07AMUTCG*	UDFN6, 1.45 x 1.0, 0.5P (Pb-Free)	3000 / Tape & Reel
NLX2G07CMUTCG*	UDFN6, 1.0 x 1.0, 0.35P (Pb-Free)	3000 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
\*In Development

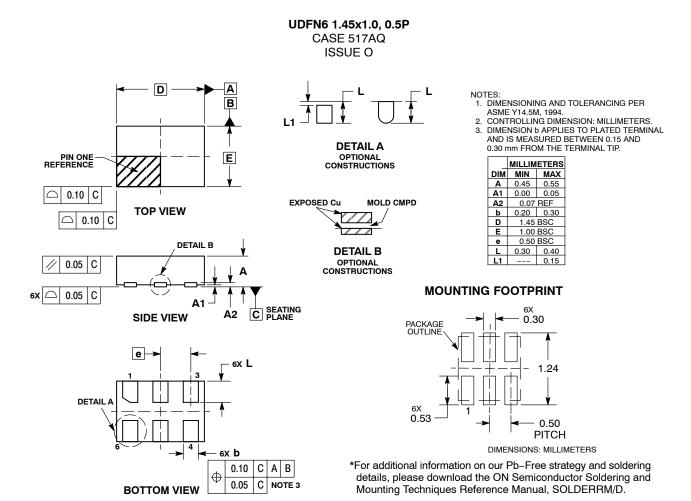
#### PACKAGE DIMENSIONS

## **UDFN6 1.2x1.0, 0.4P**CASE 517AA ISSUE O



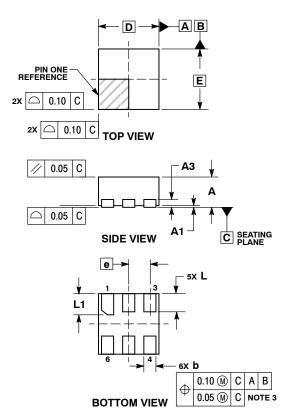
<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS



#### PACKAGE DIMENSIONS

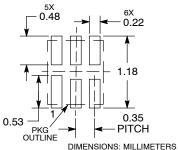
UDFN6 1.0x1.0, 0.35P CASE 517BX **ISSUE O** 



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.20 MM FROM TERMINAL TIP.
  4. PACKAGE DIMENSIONS EXCLUSIVE OF BURRS AND MOLD FLASH.

	MILLIMETERS						
DIM	MIN	MAX					
Α	0.45	0.55					
A1	0.00	0.05					
А3	0.13	REF					
b	0.12	0.22					
D	1.00 BSC						
E	1.00	BSC					
е	0.35	BSC					
L	0.25	0.35					
L1	0.30	0.40					

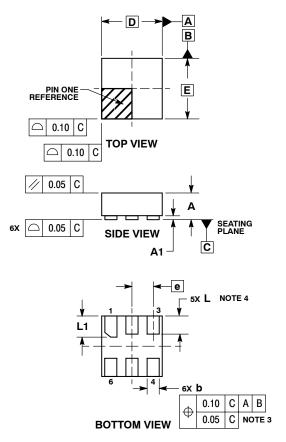
## RECOMMENDED SOLDERING FOOTPRINT\*



\*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

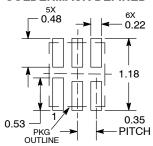
ULLGA6 1.0x1.0, 0.35P CASE 613AD ISSUE A



- NOTES:
  1. DIMENSIONING AND TOLERANCING PER
  ASME Y14.5M, 1994.
  2. CONTROLLING DIMENSION: MILLIMETERS.
  3. DIMENSION b APPLIES TO PLATED TERMINAL
  AND IS MEASURED BETWEEN 0.15 AND
  0.30 mm FROM THE TERMINAL TIP.
  4. A MAXIMUM OF 0.05 PULL BACK OF THE
  PLATED TERMINAL FROM THE EDGE OF THE
  PACKAGE IS ALLOWED.
  - PACKAGE IS ALLOWED.

_	MILLIMETERS					
DIM	MIN	MAX				
Α	-	0.40				
A1	0.00	0.05				
b	0.12	0.22				
D	1.00	BSC				
E	1.00	BSC				
е	0.35 BSC					
Ĺ	0.25	0.35				
L1	0.30	0.40				

#### **MOUNTING FOOTPRINT SOLDERMASK DEFINED\***

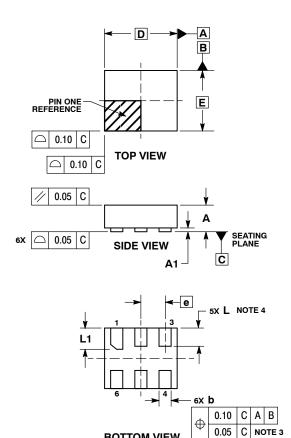


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### **PACKAGE DIMENSIONS**

ULLGA6 1.2x1.0, 0.4P CASE 613AE ISSUE A



**BOTTOM VIEW** 

#### NOTES:

- NOTES:

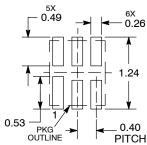
  1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.

  2. CONTROLLING DIMENSION: MILLIMETERS.

  3. DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm EPOLM TUE TERMINAL TIP.
- 0.30 mm FROM THE TERMINAL TIP.
  A MAXIMUM OF 0.05 PULL BACK OF THE
  PLATED TERMINAL FROM THE EDGE OF THE
  PACKAGE IS ALLOWED.

	MILLIM	MILLIMETERS						
DIM	MIN	MAX						
Α		0.40						
A1	0.00	0.05						
b	0.15	0.25						
D	1.20	BSC						
E	1.00	BSC						
е	0.40	BSC						
L	0.25	0.35						
L1	0.35	0.45						

#### **MOUNTING FOOTPRINT** SOLDERMASK DEFINED\*

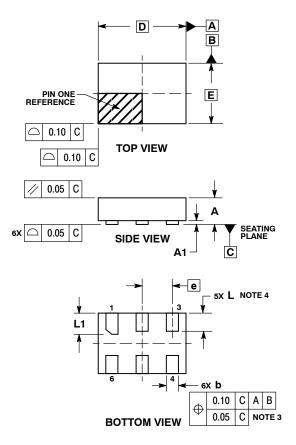


DIMENSIONS: MILLIMETERS

<sup>\*</sup>For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

#### PACKAGE DIMENSIONS

ULLGA6 1.45x1.0, 0.5P CASE 613AF **ISSUE A** 

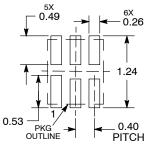


#### NOTES:

- DIMENSIONING AND TOLERANCING PER
- ASME Y14.5M, 1994.
  CONTROLLING DIMENSION: MILLIMETERS.
  DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP. A MAXIMUM OF 0.05 PULL BACK OF THE PLATED TERMINAL FROM THE EDGE OF THE
- PACKAGE IS ALLOWED.

	MILLIMETERS					
DIM	MIN	MAX				
Α		0.40				
A1	0.00	0.05				
b	0.15	0.25				
D	1.45 BSC					
Е	1.00 BSC					
е	0.50 BSC					
L	0.25	0.35				
L1	0.30	0.40				

#### MOUNTING FOOTPRINT **SOLDERMASK DEFINED\***



DIMENSIONS: MILLIMETERS

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